

East of USPB USPT, WPID, JPO

L Number	Hits	Search Text	DB	Time stamp
11	204	dual with gate with nitride	USPAT; US-PGPUB	2004/07/04 22:07
12	2200535	etch\$ or remov\$ or patern\$	USPAT; US-PGPUB	2004/07/04 22:08
13	85	(dual with gate with nitride) same (etch\$ or remov\$ or patern\$)	USPAT; US-PGPUB	2004/07/04 22:01
14	135031	"si3n4" or nitride or "si.sub.3.n.sub.4" or ("si.sub.3" with "n.sub.4")	USPAT; US-PGPUB	2004/07/04 22:08
15	39408	(etch\$ or remov\$ or patern\$) with ("si3n4" or nitride or "si.sub.3.n.sub.4" or ("si.sub.3" with "n.sub.4"))	USPAT; US-PGPUB	2004/07/04 22:02
16	69	((dual with gate with nitride) same (etch\$ or remov\$ or patern\$)) same ((etch\$ or remov\$ or patern\$) with ("si3n4" or nitride or "si.sub.3.n.sub.4" or ("si.sub.3" with "n.sub.4")))	USPAT; US-PGPUB	2004/07/04 22:02
17	0	"dual gate nitride"	USPAT; US-PGPUB	2004/07/04 22:03
18	209	"dual gate oxide"	USPAT; US-PGPUB	2004/07/04 22:04
19	0	"dual gate nitride"	JPO; DERWENT	2004/07/04 22:03
20	0	((dual with gate with nitride) same (etch\$ or remov\$ or patern\$)) same ((etch\$ or remov\$ or patern\$) with ("si3n4" or nitride or "si.sub.3.n.sub.4" or ("si.sub.3" with "n.sub.4")) and "dual gate oxide"	JPO; DERWENT	2004/07/04 22:04
21	0	((dual with gate with nitride) same (etch\$ or remov\$ or patern\$)) and "dual gate oxide"	JPO; DERWENT	2004/07/04 22:04
22	7	((dual with gate with nitride) same (etch\$ or remov\$ or patern\$)) and "dual gate oxide"	USPAT; US-PGPUB	2004/07/04 22:04
23	7	((dual with gate with nitride) same (etch\$ or remov\$ or patern\$)) same ((etch\$ or remov\$ or patern\$) with ("si3n4" or nitride or "si.sub.3.n.sub.4" or ("si.sub.3" with "n.sub.4")) and ((dual with gate with nitride) same (etch\$ or remov\$ or patern\$)) and "dual gate oxide")	USPAT; US-PGPUB	2004/07/04 22:07
24	53	dual with gate with nitride	JPO; DERWENT	2004/07/04 22:07
25	1602183	etch\$ or remov\$ or patern\$	JPO; DERWENT	2004/07/04 22:08
26	106739	"si3n4" or nitride or "si.sub.3.n.sub.4" or ("si.sub.3" with "n.sub.4")	JPO; DERWENT	2004/07/04 22:08
27	29	(dual with gate with nitride) and (etch\$ or remov\$ or patern\$) and ("si3n4" or nitride or "si.sub.3.n.sub.4" or ("si.sub.3" with "n.sub.4"))	JPO; DERWENT	2004/07/04 22:08